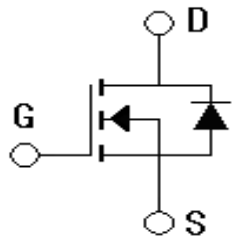
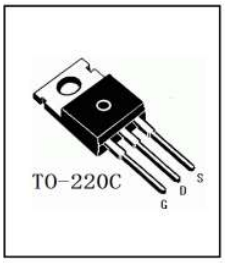
JCS3205H

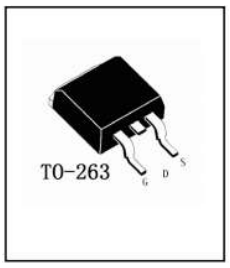
主要参数 MAIN CHARACTERISTICS

I_D	110 A
V_{DSS}	55 V
Rdson-max （@Vgs=10V）	8 mΩ
Qg-typ	78nC

封装 Package







用途

- 高频开关电源
- UPS 电源

APPLICATIONS

- High efficiency switch mode power supplies
- UPS

产品特性

- 低栅极电荷
- 低 C_{rss} (典型值 197pF)
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品

FEATURES

- Low gate charge
- Low C_{rss} (typical 197pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

订货信息 ORDER MESSAGE

订 货 型 号 Order codes				印 记 Marking	封 装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen-Free-Tube	有卤-编带 Halogen-Reel	无卤-编带 Halogen-Free-Reel		
JCS3205CH-C-B	JCS3205CH-C-BR	N/A	N/A	JCS3205CH	TO-220C
JCS3205SH-S-B	JCS3205SH-S-BR	JCS3205SH-S-A	JCS3205SH-S-AR	JCS3205SH	TO-263

绝对最大额定值 ABSOLUTE RATINGS (Tc=25℃)

项　　目 Parameter	符　号 Symbol	数　值 Value	单　位 Unit
最高漏极－源极直流电压 Drain-Source Voltage	V_{DSS}	55	V
连续漏极电流 Drain Current -continuous	I_D T=25℃	110*	A
	T=100℃	80*	A
最大脉冲漏极电流（注 1） Drain Current – pulse（note 1）	I_{DM}	440*	A
最高栅源电压 Gate-Source Voltage	V_{GSS}	±20	V
单脉冲雪崩能量（注 2） Single Pulsed Avalanche Energy（note 2）	E_{AS}	2970	mJ
雪崩电流（注 1） Avalanche Current（note 1）	I_{AR}	60	A
重复雪崩能量（注 1） Repetitive Avalanche Current（note 1）	E_{AR}	20	mJ
二极管反向恢复最大电压变化速率（注 3） Peak Diode Recovery dv/dt（note 3）	dv/dt	5.0	V/ns
耗散功率 Power Dissipation	P_D T_C=25℃	200	W
	-Derate above 25℃	1.33	W/℃
最高结温及存储温度 Operating and Storage Temperature Range	T_J，T_{STG}	-55～+175	℃
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T_L	300	℃

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature

电特性 ELECTRICAL CHARACTERISTICS

项　　目 Parameter	符　号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单位 Units
关态特性 Off –Characteristics						
漏－源击穿电压 Drain-Source Voltage	BV_{DSS}	I_D=250μA, V_{GS}=0V	55	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\Delta BV_{DSS}/\Delta T_J$	I_D=250μA, referenced to 25℃	-	0.057	-	V/℃
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=55V,V_{GS}=0V, T_C=25℃	-	-	1	μA
		V_{DS}=44V, T_C=125℃	-	-	10	μA
正向栅极体漏电流 Gate-body leakage current, forward	I_{GSSF}	V_{DS}=0V, V_{GS} =20V	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	I_{GSSR}	V_{DS}=0V, V_{GS} =-20V	-	-	-100	nA
通态特性 On-Characteristics						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS} , I_D=250μA	2.0	-	4.0	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$ T=25℃	V_{GS} =10V , I_D=60A	-	7	8	mΩ
	$R_{DS(ON)}$ T=100℃	V_{GS} =10V , I_D=60A	-	10.5	12	mΩ
正向跨导 Forward Transconductance	g_{fs}	V_{DS} = 28V, I_D=60A（note 4）	-	43	-	S
动态特性 Dynamic Characteristics						
栅电阻 Gate Resistance	R_g	f=1.0MHz, V_{DS} OPEN	0.5	1.8	2.6	Ω
输入电容 Input capacitance	C_{iss}	V_{DS}=25V, V_{GS} =0V, f=1.0MHz	1375	2750	5625	pF
输出电容 Output capacitance	C_{oss}		375	749	1124	pF
反向传输电容 Reverse transfer capacitance	C_{rss}		99	197	296	pF

电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics						
延迟时间 Turn-On delay time	$t_d(on)$	V_{DD}=28V,I_D=60A,R_G=25Ω	-	17	26	ns
上升时间 Turn-On rise time	t_r	V_{GS} =10V	-	122	183	ns
延迟时间 Turn-Off delay time	$t_d(off)$	（note 4，5）	-	57	86	ns
下降时间 Turn-Off Fall time	t_f		-	72	108	ns
栅极电荷总量 Total Gate Charge	Q_g	V_{DS} =44V ,	38	78	117	nC
栅－源电荷 Gate-Source charge	Q_{gs}	I_D=60A	6.6	13.2	20	nC
栅－漏电荷 Gate-Drain charge	Q_{gd}	V_{GS} =10V （note 4，5）	18.9	37.8	56	nC
漏－源二极管特性及最大额定值 **Drain-Source Diode Characteristics and Maximum Ratings**						
正向最大连续电流 Maximum Continuous Drain -Source Diode Forward Current	I_S		-	-	110	A
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current	I_{SM}		-	-	440	A
正向压降 Drain-Source Diode Forward Voltage	V_{SD}	V_{GS}=0V, I_S=60A	-		1.3	V
反向恢复时间 Reverse recovery time	t_{rr}	V_{GS}=0V, I_S=60A	-	67	127	ns
反向恢复电荷 Reverse recovery charge	Q_{rr}	dI_F/dt=100A/μs (note 4)	-	163	253	nC

热特性 THERMAL CHARACTERISTIC

项 目 **Parameter**	符 号 **Symbol**	最大 **Max**	单 位 **Unit**
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	0.75	℃/W
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	62.5	℃/W

注释：

1：脉冲宽度由最高结温限制

2：L=0.5mH, I_{AS}=60A, V_{DD}=50V, R_G=25 Ω,起始结温 T_J=25℃

3：I_{SD} ≤60A,di/dt ≤300A/μs,VDD≤BV_{DSS},起始结温 T_J=25℃

4：脉冲测试：脉冲宽度≤300μs,占空比≤2%

5：基本与工作温度无关

Notes:

1：Pulse width limited by maximum junction temperature

2：L=0.5mH, I_{AS}=60A, V_{DD}=50V, R_G=25 Ω,Starting T_J=25℃

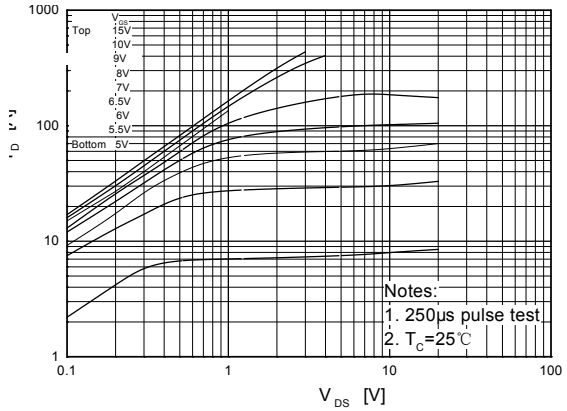
3：I_{SD} ≤60A,di/dt ≤300A/μs,VDD≤BV_{DSS}, Starting T_J=25℃

4：Pulse Test：Pulse Width ≤300μs,Duty Cycle≤2%

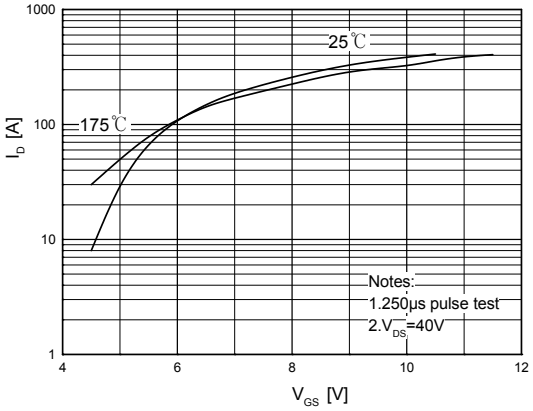
5：Essentially independent of operating temperature

特征曲线 ELECTRICAL CHARACTERISTICS (curves)

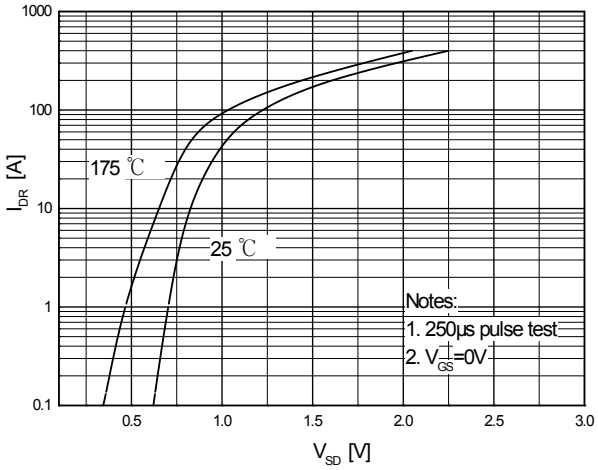
On-Region Characteristics



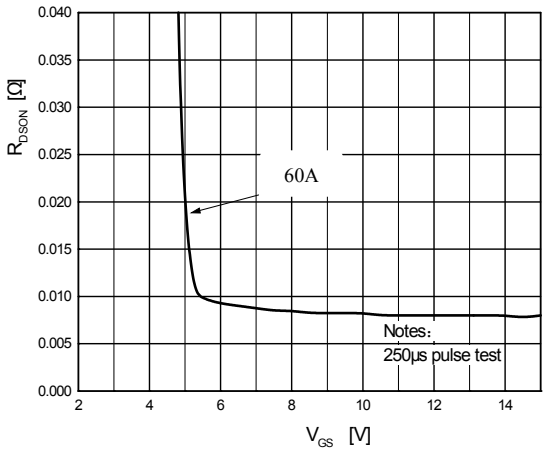
Transfer Characteristics



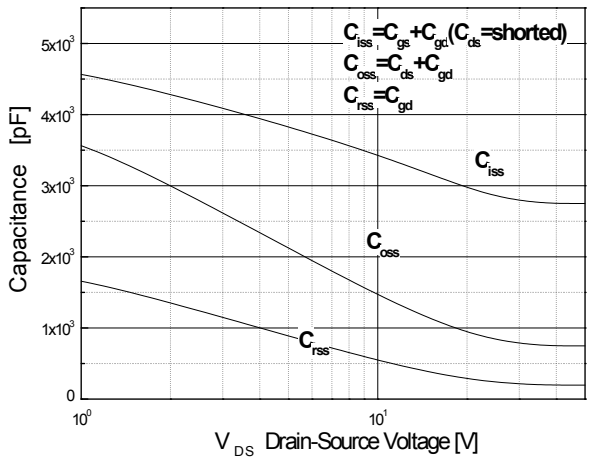
Body Diode Forward Voltage Variation vs. Source Current and Temperature



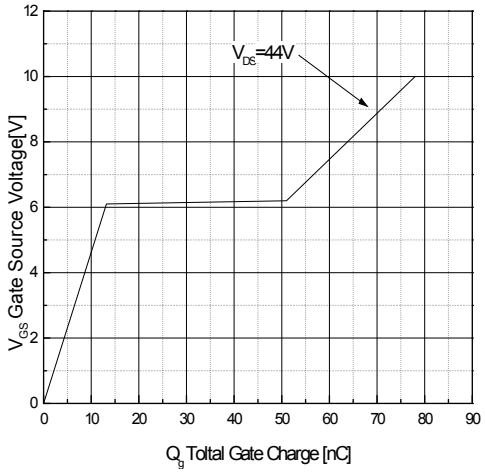
On-Resistance Variation vs. Drain Current and Gate Voltage



Capacitance Characteristics

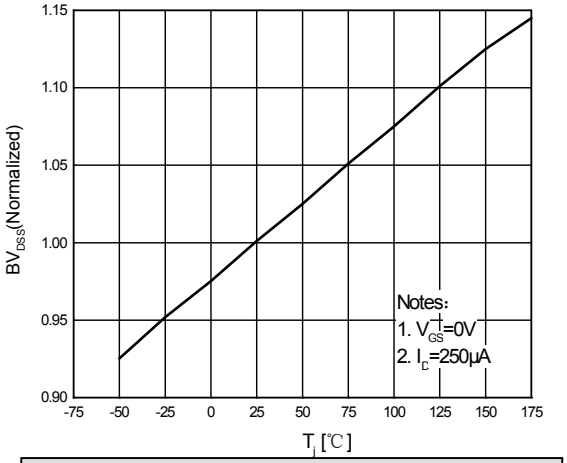


Gate Charge Characteristics

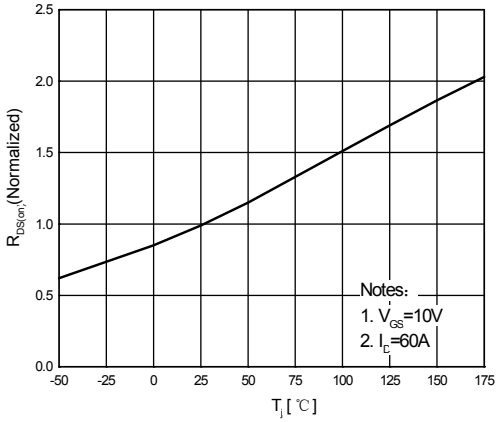


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

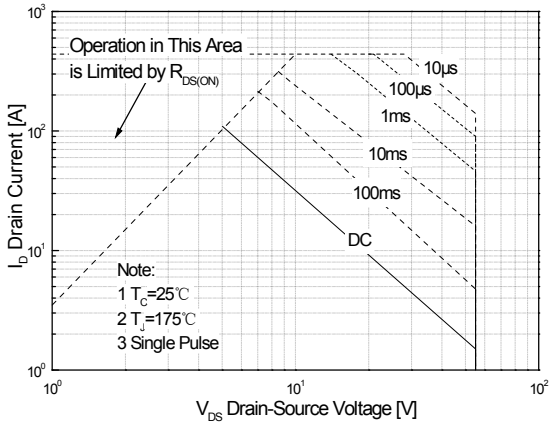
Breakdown Voltage Variation vs. Temperature



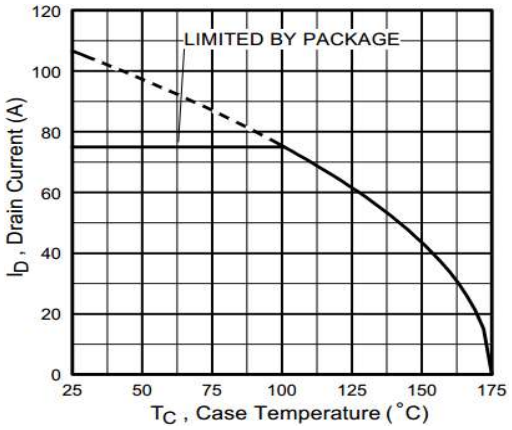
On-Resistance Variation vs. Temperature



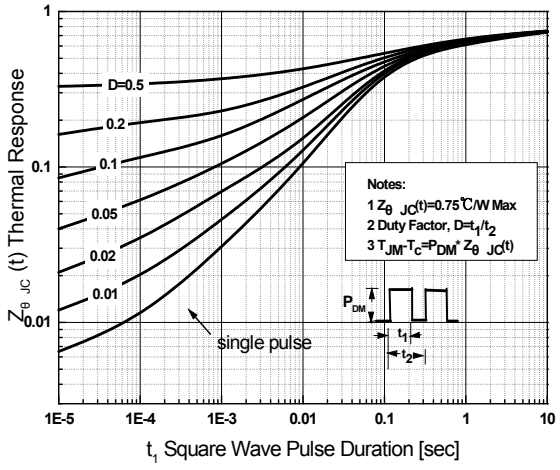
Maximum Safe Operating Area For JCS3205H



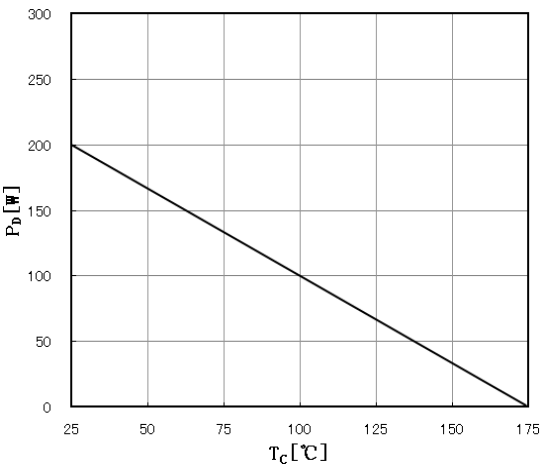
Maximum Drain Current vs. Case Temperature



Transient Thermal Response Curve For JCS3205H



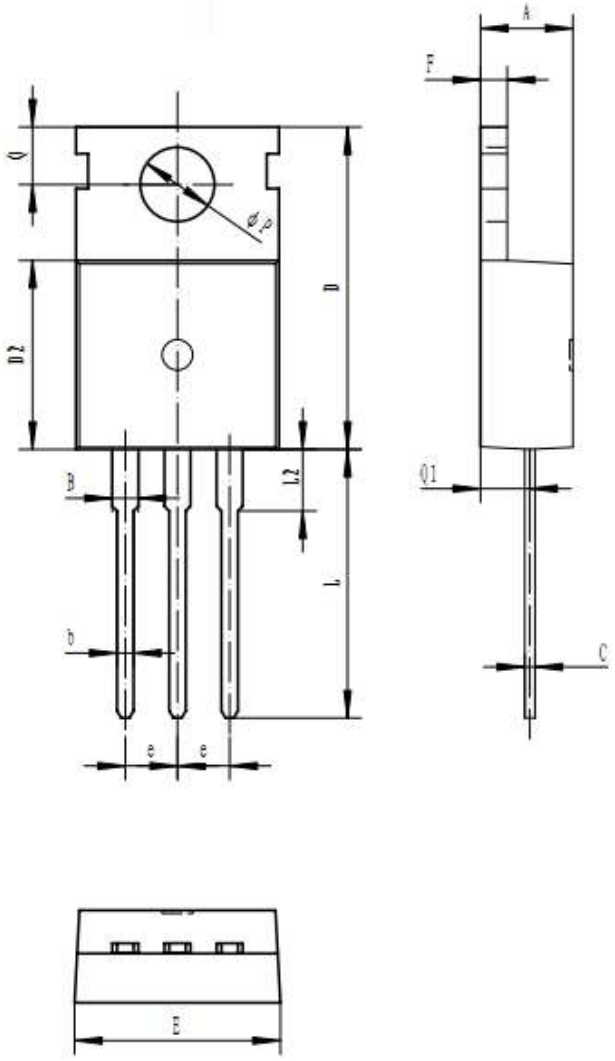
Power Dissipation vs. Case Temperature



外形尺寸 PACKAGE MECHANICAL DATA

TO-220C

单位 Unit：mm

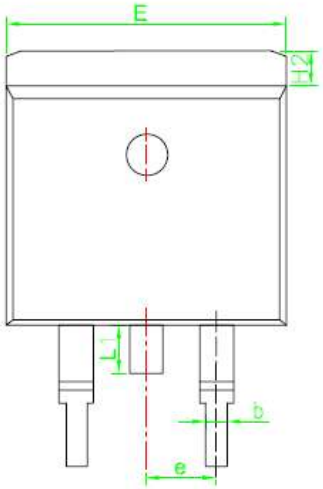


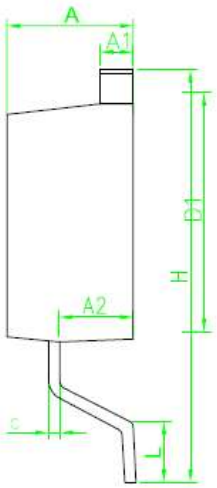
符号 symbol	MIN	MAX
A	4.30	4.70
B	1.22	1.40
b	0.70	0.95
c	0.40	0.65
D	15.20	16.20
D2	9.00	9.40
E	9.70	10.10
e	2.39	2.69
F	1.25	1.40
L	12.60	13.60
L2	2.80	3.20
Q	2.60	3.00
Q1	2.20	2.60
P	3.50	3.80

外形尺寸 PACKAGE MECHANICAL DATA

TO-263

单位 Unit：mm





SYMBOL	MM	
	MIN	MAX
A	4.30	4.80
A1	1.12	1.42
A2	2.54	2.84
b	0.67	1.00
c	0.29	0.52
D1	8.40	9.00
E	9.80	10.46
e	2.54BSC	
H	14.00	16.00
H2	1.12	1.45
L	1.50	3.10
L1	1.45	1.70

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